

Surface Mount Switching Diode

* "G" Lead(Pb)-Free

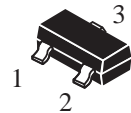
Features:

- *Fast Switching Speed
- *Surface Mount Package Ideally Suited for Automatic Insertion
- *For General Purpose Switching Applications
- *High Conductance

Mechanical Data:

- *Case: SOT-23, Molded Plastic
- *Terminals: Solderable per MIL-STD-202, Method 208
- *Polarity: See diagram
- *Weight: 0.008 grams

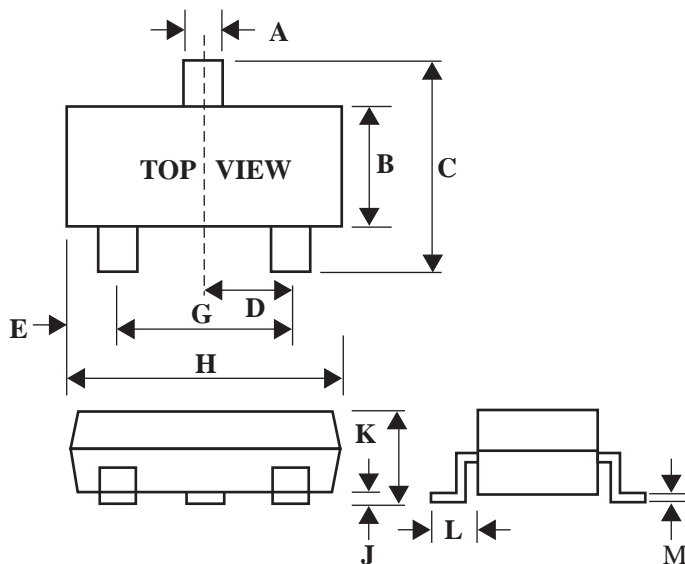
SWITCHING DIODE
100m AMPERRES
70 VOLTS



SOT-23

SOT-23 Outline Dimensions

Unit:mm



| Dim | Min | Max |
|-----|-------|------|
| A | 0.35 | 0.51 |
| B | 1.19 | 1.40 |
| C | 2.10 | 3.00 |
| D | 0.85 | 1.05 |
| E | 0.46 | 1.00 |
| G | 1.70 | 2.10 |
| H | 2.70 | 3.10 |
| J | 0.01 | 0.13 |
| K | 0.89 | 1.10 |
| L | 0.30 | 0.61 |
| M | 0.076 | 0.25 |

Maximum Ratings ((TA=25°C Unless Otherwise Note)

| Characteristic | Symbol | Value | Unit |
|--|---|--------------|-------|
| Non-Repetitive Peak Reverse Voltage | V _{RM} | 100 | Volts |
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RW} V _R | 70 | Volts |
| RMS Reverse Voltage | V _{R(RMS)} | 53 | Volts |
| Forward Continuous Current ⁽¹⁾ | I _{FM} | 100 | mA |
| Non-Repetitive Peak Forward @ t=1.0us Surge Current @ t=1.0s | I _{FSM} | 2.0 1.0 | A |
| Power Dissipation ⁽¹⁾ | P _d | 350 | mW |
| Thermal Resistance Junction to Ambient Air ⁽¹⁾ | R _{θJA} | 357 | °C/W |
| Operating and Storage Temperature Range | T _j , T _{STG} | -65 to + 150 | °C |

Electrical Characteristics (TA=25°C Unless Otherwise Note) (Each Diode)

| Characteristic | Symbol | Min | Max | Unit |
|----------------|--------|-----|-----|------|
|----------------|--------|-----|-----|------|


Off Characteristics

| | | | | | |
|--------------------------------|--|-----------------|---|-------------------------------|----------------------|
| Forward Voltage ⁽²⁾ | I _F =1.0mA I _F =10mA I _F =50mA I _F =150mA | V _F | - | 0.715 0.855 1.0 1.25 | Volts |
| Reverse Current ⁽²⁾ | V _R =70V V _R =75V, T _j =150°C V _R =25V, T _j =150°C V _R =20V | I _R | - | 2.5 50 30 25 | uA uA uA nA |
| Total Capacitance | V _R =0, f=1.0MHz | C _T | - | 2.0 | Pf |
| Reverse Recovery Time | I _F =I _R =10mA, I _{rr} =0.1×I _R , R _L =100Ω | t _{rr} | - | 6.0 | ns |

Note:

1. Part mounted on FR-4 board with recommended pad layout.
2. Short duration pulse test used to minimize self-heating effect.

Device Marking

| Item | Marking | Equivalent Circuit diagram |
|-------|---------|---|
| BAL99 | JF |  |

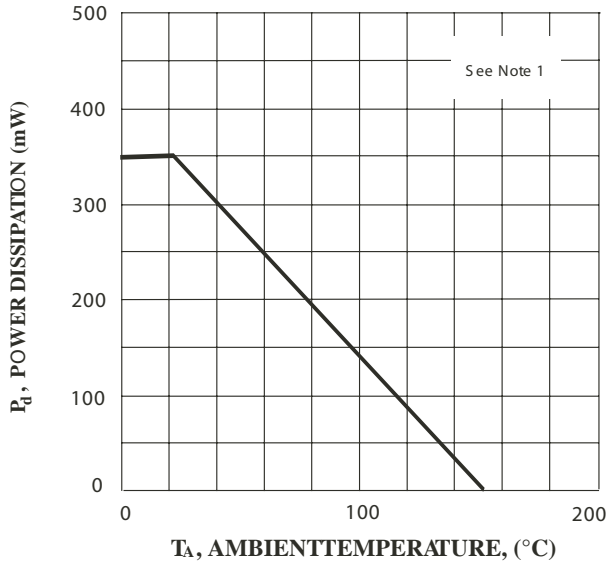


FIG1. Power Derating Curve

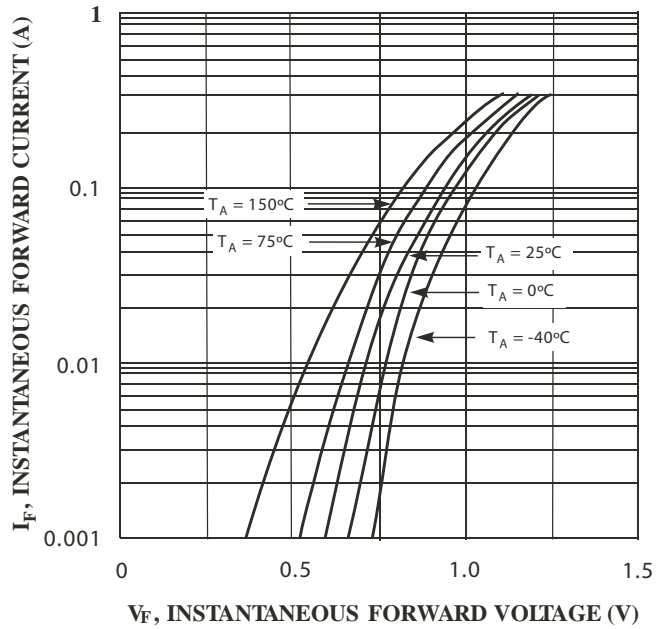


FIG2. Forward Characteristics

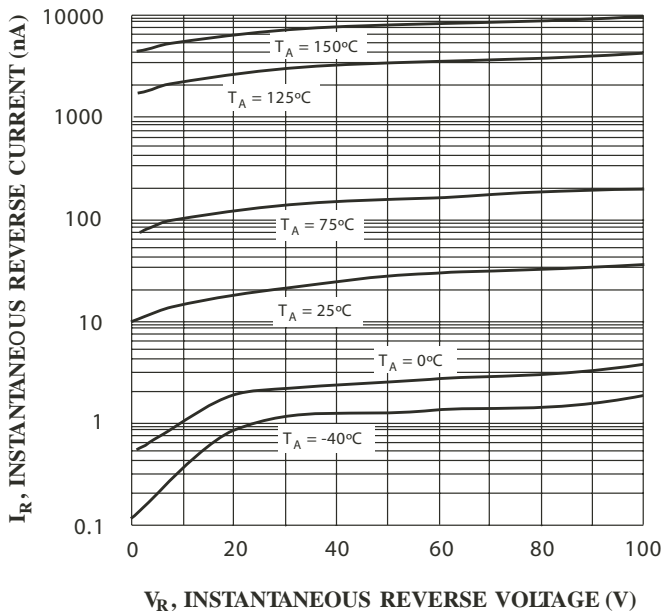


FIG3. Typical Reverse Characteristics

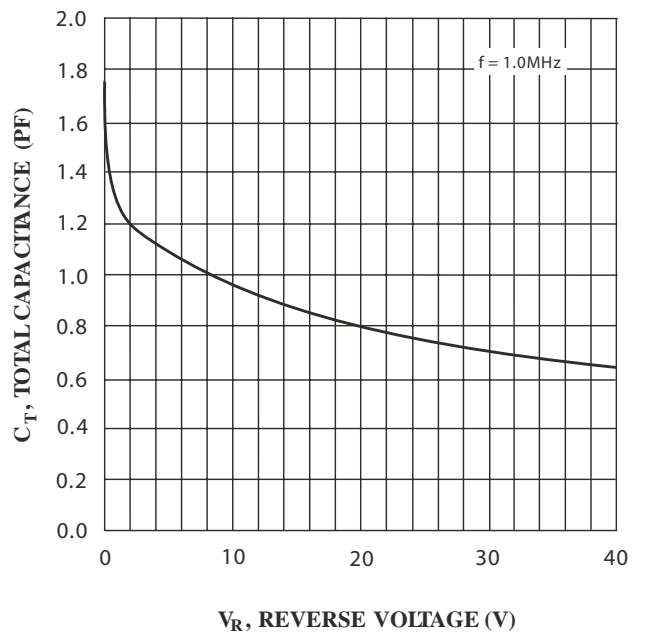


FIG4. Typical Capacitance vs. Reverse Voltage